



Ultra-Low Capacitance TVS Protection

Features

Transient protection for high-speed data lines
 IEC 61000-4-2 (ESD) ±20kV (Air)
 ±20kV (Contact)

IEC 61000-4-5 (Surge) 4A (8/20μs)

- For 5V and below operating voltage
- Small package: DFN1.2*1.0-6
- Protects two data lines
- Low Cap: 0.3pF Typ. (I/O-I/O) 0.6pF Typ. (I/O-GND)
- Low leakage current: 0.1μA @ V_{RWM} (Typ.)
- Low clamping voltage
- Each I/O pin can withstand over 1000 ESD strikes for ±8kV contact discharge

Description

SYT03S05SHC is an ultra-low capacitance Transient Voltage Suppressor (TVS) designed to provide electrostatic discharge (ESD) protection for high-speed data interfaces. With typical capacitance of $0.3 \mathrm{pF}(\mathrm{I/O\text{-I/O}})$ only, SYT03S05SHC is designed to protect parasitic-sensitive systems against over-voltage and over-current transient events. It complies with IEC 61000-4-2 (ESD), ($\pm 20 \mathrm{kV}$ air, $\pm 20 \mathrm{kV}$ contact discharge), IEC 61000-4-5 (Surge) (4A, 8/20 μ s), etc.

SYT03S05SHC uses small DFN1.2*1.0-6 package. Each SYT03S05SHC device can protect two high-speed data lines. The combined features of low capacitance, small size and high ESD robustness make SYT03S05SHC ideal for high-speed data ports and high-frequency lines (e.g., USB2.0 & DVI) applications. The low clamping voltage of the SYT03S05SHC guarantees a minimum stress on the protected IC.

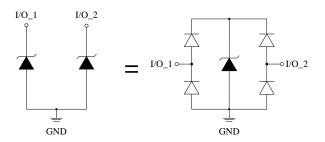
Applications

- Serial ATA
- PCI Express
- Desktops, Servers and Notebooks
- MDDI Ports
- USB2.0 Power and Data Line Protection
- Display Ports
- Digital Visual Interfaces (DVI)

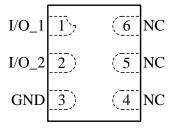
Mechanical Characteristics

- DFN1.2*1.0-6 package
- Marking: Device code, Date code
- Packaging: Tape and Reel

Circuit Diagram



Pin Configuration



DFN1.2*1.0-6 (Top View)

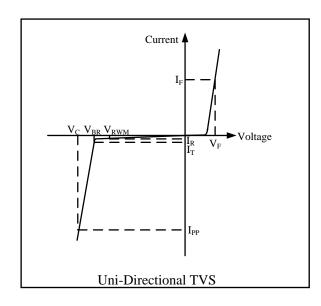


Absolute Maximum Rating

Symbol	Parameter	Value	Units	
V_{ESD}	ESD per IEC 61000-4-2 (Air)	±20	kV	
	ESD per IEC 61000-4-2 (Contact)	±20		
I_{PP}	Maximum Peak Pulse Current (8/20μs)	4	A	
T_{OPT}	Operating Temperature	-40/+125	°C	
T_{STG}	Storage Temperature	-55/+150	°C	

Electrical Characteristics $(T = 25^{\circ}C)$

Symbol	Parameter		
V_{RWM}	Nominal Reverse Working Voltage		
I_R	Reverse Leakage Current @ V _{RWM}		
V_{BR}	Reverse Breakdown Voltage @ I _T		
I_{T}	Test Current for Reverse Breakdown		
V_{C}	Clamping Voltage @ I _{PP}		
I_{PP}	Maximum Peak Pulse Current		
C _{ESD}	Parasitic Capacitance		
V_R	Reverse Voltage		
f	Small Signal Frequency		
I_{F}	Forward Current		
V_{F}	Forward Voltage @ I _F		



2

Symbol	Test Condition	Minimum	Typical	Maximum	Units
V_{RWM}				5.0	V
I_R	$V_{RWM} = 5V$, from I/O to GND		0.1	1	μΑ
V_{BR}	$I_T = 1$ mA, from I/O to GND	6		11	V
V_{F}	$I_F = 1$ mA, from GND to I/O	0.4		1.2	V
V_{C^1}	$I_{PP}=4A$, $t_p=8/20\mu s$, from I/O to GND		12		V
V_C^1	$I_{PP} = 16A$, $t_p = 10/100$ ns, from I/O to GND		14		V
$R_{\mathrm{DYN}}^{1,2}$	$t_p = 10/100$ ns, from I/O to GND		0.4		Ω
C _{ESD} ¹	$V_R = 0V$, $f = 1MHz$, Between I/O and GND		0.6	0.8	pF
C _{ESD} ¹	$V_R = 0V$, $f = 1MHz$, Between I/O and I/O		0.3	0.4	pF

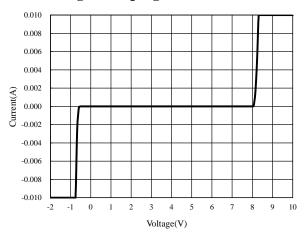
NOTES

¹Guaranteed by design and not subject to production test.

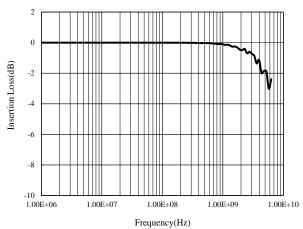
 $^{^2}R_{\rm DYN}$ calculated based on Ipp=8A to Ipp=16A, $t_p=10/100ns.$



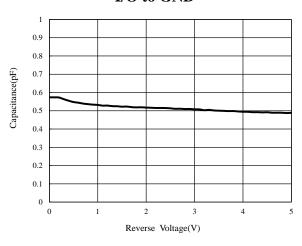
Voltage Sweeping of I/O to GND



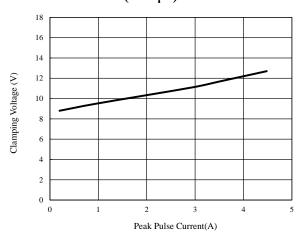
Insertion Loss S21 of I/O to GND



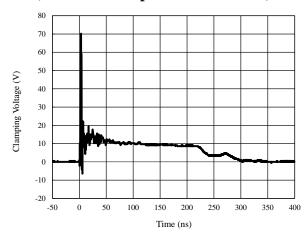
Capacitance vs. Voltage - I/O to GND



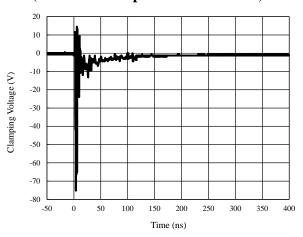
Clamping Voltage vs. Peak Pulse Current (8/20µs)



ESD Clamping of I/O to GND (+8kV Contact per IEC 61000-4-2)



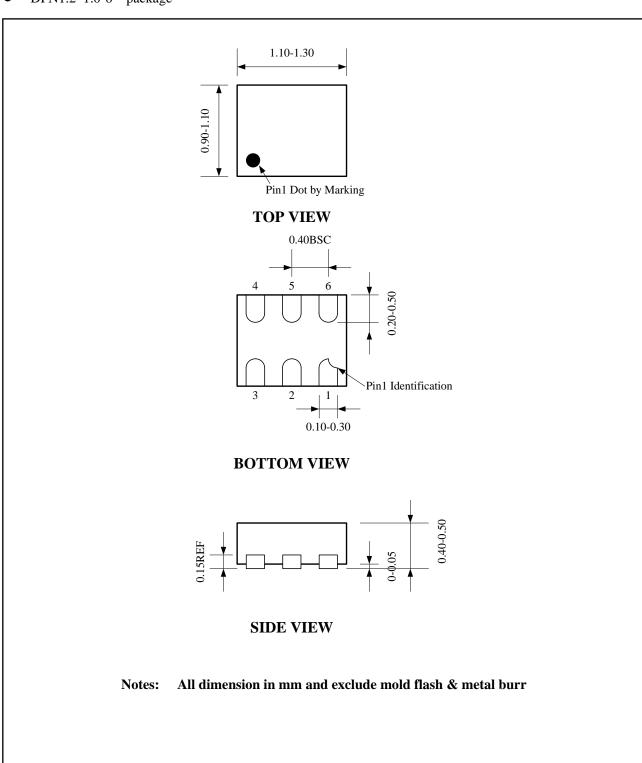
ESD Clamping of I/O to GND (-8kV Contact per IEC 61000-4-2)





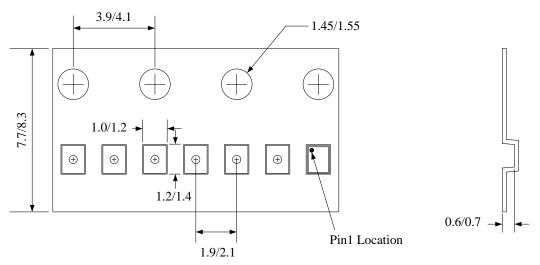
Package Outline

• DFN1.2*1.0-6 package





Tape and Reel Specification

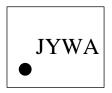


Dimensions In mm

Feeding direction ————

Package types	Tape width (mm)	Pocket pitch(mm)	Reel size (Inch)	Qty per reel (pcs)
DFN1.2*1.0-6	8	4	7"	3000

Marking Codes



Note:

- (1) "J" is the device marking, fixed.
- (2) "YWA" is date code.

Ordering Information

Part Number	Package	Quantity Per Reel	Reel Size
SYT03S05SHC	DFN1.2*1.0-6	3,000	7 Inch

单击下面可查看定价,库存,交付和生命周期等信息

>>SILERGY(矽力杰)